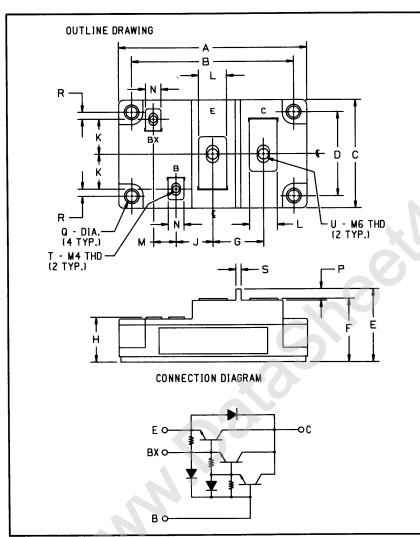


KS621220A7

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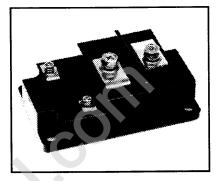
Single Darlington Transistor Module 200 Amperes/1200 Volts



Outline Drawing

Dimensions	inches	Millimeters		
Α	4.252 Max.	108 Max.		
В	3.661 ± 0.012	93 ± 0.3		
С	2.441 Max.	62 Max.		
D	1.89 ± 0.012	48 ± 0.3		
E	1.634 Max.	41.5 Max.		
F	1.417 Max.	36 Max.		
G	1.142	29		
Н	1.004	25.5		
J	0.827	21		
ĸ	0.787	20		

Dimensions	Inches	Millimeters
L	0.630	16
М	0.512	13
N	0.354	9
Р	0.256	6.5
Q	0.256 Dia.	6.5 Dia.
R	0.157	4
S	0.118	3
т	M4 Metric	M4
U	M6 Metric	M6



Description:

The Powerex Single Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of one Darlington Transistor with a reverse parallel connected highspeed diode and base-to-emitter speed-up diode.

Features:

- Solated Mounting
- Planar Chips
- Discrete Fast Recovery
- Feedback Diode
- High Gain (h_{FE})
- Base-Emitter Speed-up Diode

Applications:

- Inverters
- DC Motor Control
- Switching Power Supplies
- AC Motor Control

Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KS621220A7 is a 1200 Volt, 200 Ampere Single Darlington Module with a gain of 75 at rated current (200 Amperes).

Туре	V _{CEO(sus)} Volts (X 100)	Current Rating Amperes (X 10)
KS62	12	20



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Absolute Maximum Ratings, T_j = 25 °C unless otherwise specified

Ratings	Symbol	KS621220A7	Units
Junction Temperature		-40 to 150	°C
Storage Temperature	T _{stg}	-40 to 125	
Collector-Emitter Sustaining Voltage, V _{BE} = -2V	V _{CEV(sus)}	1200	Volts
Collector-Base Voltage	V _{CBO}	1200	Volts
Emitter-Base Voltage	VEBO	7	Volts
Collector-Emitter Voltage	V _{CEV}	1200	Volts
Continuous Collector Current	lc	200	Amperes
Diode Forward Current	I _{FM}	200	Amperes
Continuous Base Current	l _B	10	Amperes
Diode Surge Current	I _{FSM}	2000	Amperes
Power Dissipation	P _t	1560	Watts
Max. Mounting Torque M6 Terminal Screws (E, C)		26	inlb.
Max. Mounting Torque M4 Terminal Screws (B, Bx)		12	inlb.
Max. Mounting Torque M6 Mounting Screws	_	26	inlb.
Modular Weight (Typical)	_	470	Grams
V Isolation	V _{RMS}	2500	Volts

Electrical Characteristics, T_i = 25 °C unless otherwise specified

Characteristics		Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutol	ff Current	ICEV	V _{CE} = 1200V, V _{BE} = -2V	-	-	4	mA
			$V_{CE} = 1200V, V_{BE} = -2V, T_{C} = 125^{\circ}C$			40	mA
Emitter Cutoff	Current	I _{EBO}	V _{EB} = 7V			800	mA
DC Current Ga	un	h _{FE}	I _C = 200A, V _{CE} = 5.0V	100			_
Diode Forward	Voltage	V _{FM}	I _{FM} = 200A	_		1.8	Volts
Collector-Emitt	er Saturation Voltage	V _{CE(sat)}	I _C = 200A, I _B = 4.0A	-	-	3.0	Volts
Base-Emitter S	aturation Voltage	V _{BE(sat)}	$I_{\rm C} = 200$ A, $I_{\rm B} = 4.0$ A		-	3.5	Volts
Resistive	Turn-on	t _{on}	$V_{CC} = 600V$			3.0	μS
Load	Storage Time	t _s	I _C = 200A		_	15	μS
Switch Times	Fall Time	tr	I _{B1} = 4A, I _{B2} = -4A	_	_	3.0	μ.s

Thermal and Mechanical Characteristics, $T_j = 25$ °C unless otherwise specified

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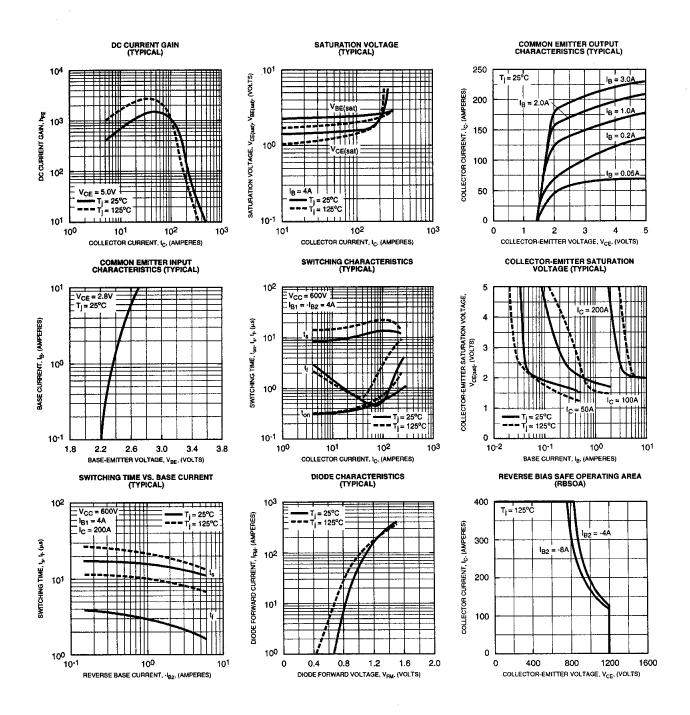
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Case-to-Sink	R _{θ(c-s)}	· · · · · · · · · · · · · · · · · · ·		_	0.04	°C/W
Thermal Resistance, Junction-to-Case	R _{θ(j-c)}	Transistor Part	_	_	0.8	°C/W
Thermal Resistance, Junction-to-Case	R _{θ(j-c)}	Diode Part			0.35	°C/W



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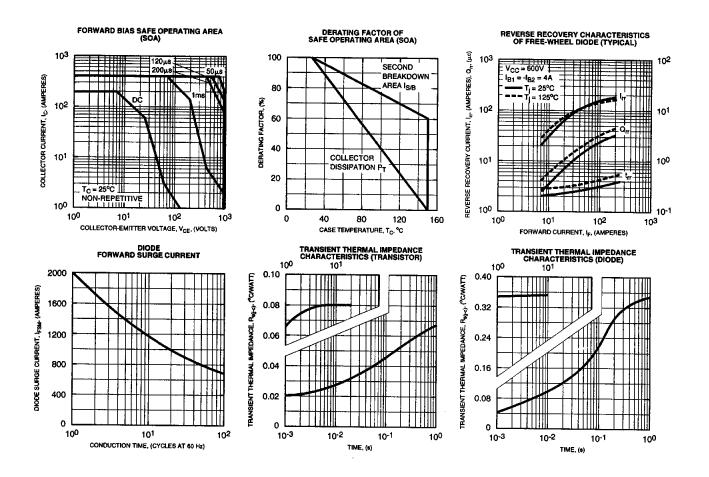




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